

NOT RECOMMENDED FOR NEW DESIGN **USE ZXTP5240F**

DSS5240T

Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
|------------------------------|------------------|-------|------|
| Collector-Base Voltage | V_{CBO} | -40 | V |
| Collector-Emitter Voltage | V _{CEO} | -40 | V |
| Emitter-Base Voltage | V _{EBO} | -5 | V |
| Peak Pulse Collector Current | I _{CM} | -3 | Α |
| Continuous Collector Current | Ic | -2 | Α |
| Base Current | Ι _Β | -300 | mA |

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
|--|----------------------|-------------|------|
| Power Dissipation (Note 6) | P _D | 730 | mW |
| Power Dissipation (Note 7) | P _D | 600 | mW |
| Thermal Resistance, Junction to Ambient Air (Note 6) | R _{OJA} | 171 | °C/W |
| Thermal Resistance, Junction to Ambient Air (Note 7) | R _{OJA} | 209 | °C/W |
| Thermal Resistance, Junction to Lead (Note 8) | Rejl | 75 | °C/W |
| Operating and Storage Temperature Range | TJ, T _{STG} | -55 to +150 | °C |

ESD Ratings (Note 9)

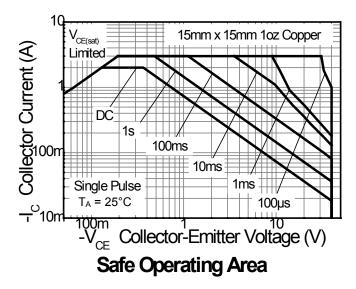
| Characteristic | Symbol | Value | Unit | JEDEC Class |
|--|---------|-------|------|-------------|
| Electrostatic Discharge—Human Body Model | ESD HBM | 4000 | V | 3A |
| Electrostatic Discharge—Machine Model | ESD MM | 400 | V | С |

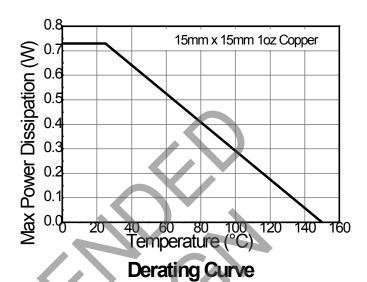
Notes:

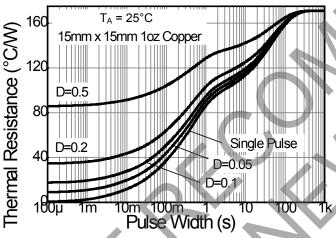
- 6. For a device mounted with the collector lead on 15mm × 15mm 1oz copper that is on a single-sided 1.6mm FR-4 PCB; device is measured under To a device mounted with the collector lead on 15mm 162 copper that is on a still air conditions whilst operating in a steady-state.
 Same as Note 6, except the device is mounted on minimum recommended pad layout.
 Thermal resistance from junction to solder-point (at the end of the collector lead).
 Refer to JEDEC specification JESD22-A114 and JESD22-A115.

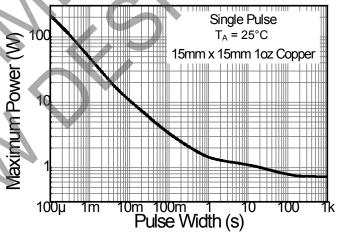


Thermal Characteristics and Derating Information









Transient Thermal Impedance

Pulse Power Dissipation

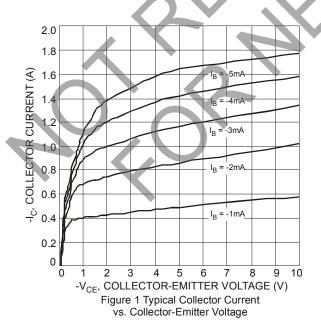


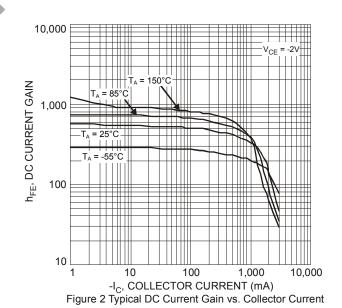
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Min | Тур | Max | Unit | Test Conditions |
|---|-----------------------|-----|----------|-------|------|--|
| OFF CHARACTERISTICS | | | | | | |
| Collector-Base Breakdown Voltage | BV _{CBO} | -40 | _ | _ | V | I _C = -100μA |
| Collector-Emitter Breakdown Voltage (Note 10) | BV _{CEO} | -40 | _ | _ | V | I _C = -10mA |
| Emitter-Base Breakdown Voltage | BV _{EBO} | -5 | _ | _ | V | I _E = -100μA |
| Collector-Base Cutoff Current | I _{CBO} | | _ | -100 | nA | $V_{CB} = -30V, I_{E} = 0$ |
| Collector-base Cuton Current | | | _ | -50 | μA | $V_{CB} = -30V$, $I_E = 0$, $T_A = +150$ °C |
| Emitter-Base Cutoff Current | I _{EBO} | _ | _ | -100 | nA - | $V_{EB} = -4V, I_{C} = 0$ |
| ON CHARACTERISTICS (Note 10) | | | | | | |
| | | 300 | _ | _ | | $V_{CE} = -2V, I_{C} = -0.1A$ |
| DC Current Gain | h | 260 | _ | _ | X | V _{CE} = -2V, I _C = -0.5A |
| DC Current Gain | h _{FE} | 210 | _ | - | 7 | V _{CE} = -2V, I _C = -1A |
| | | 100 | _ | 1-1 | | V _{CE} = -2V, I _C = -2A |
| | V _{CE} (SAT) | 1 | _ | -100 | | $I_C = -100 \text{mA}, I_B = -1 \text{mA}$ |
| | | - | -45 | -110 | | $I_C = -500$ mA, $I_B = -50$ mA |
| Collector-Emitter Saturation Voltage | | _ | / | -225 | mV | $I_C = -750 \text{mA}, I_B = -15 \text{mA}$ |
| | | _ | | -225 | ~ \ | $I_C = -1A$, $I_B = -50mA$ |
| | | -// | | -350 | | $I_C = -2A$, $I_B = -200mA$ |
| Equivalent On-Resistance | R _{CE(SAT)} | 7 | 90 | 220 | mΩ | $I_{\rm C}$ = -500mA, $I_{\rm B}$ = -50mA |
| Base-Emitter Saturation Voltage | $V_{BE(SAT)}$ | - | 3 - | -1.1 | V | I _C = -2A, I _B = -200mA |
| Base-Emitter Turn-on Voltage | V _{BE(ON)} | 1-1 | | -0.75 | V | V _{CE} = -2V, I _C = -100mA |
| SMALL SIGNAL CHARACTERISTICS | | | | | | |
| Transition Frequency | f⊤ | 100 | | | MHz | V _{CE} = -10V, I _C = -100mA, f = 100MHz |
| Output Capacitance | C_{obo} | | | 28 | pF | V _{CB} = -10V, f = 1MHz |

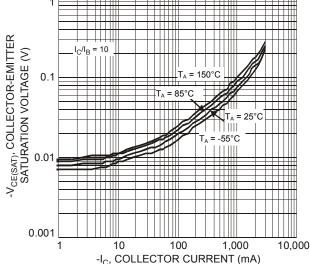
Note: 10. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.

Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

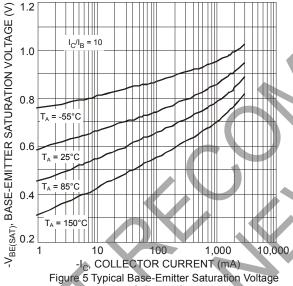








-I_C, COLLECTOR CURRENT (mA)
Figure 3 Typical Collector-Emitter Saturation Voltage vs. Collector Current



vs. Collector Current

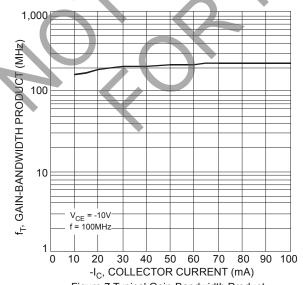
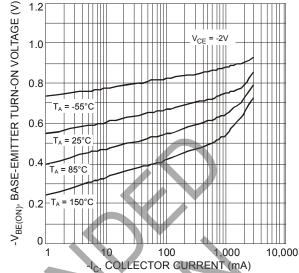


Figure 7 Typical Gain-Bandwidth Product vs. Collector Current



-I_C, COLLECTOR CURRENT (mA)
Figure 4 Typical Base-Emitter Turn-On Voltage
vs. Collector Current

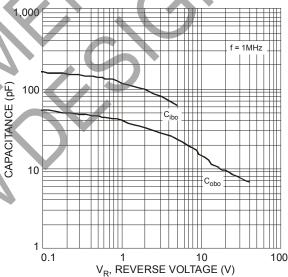


Figure 6 Typical Capacitance Characteristics

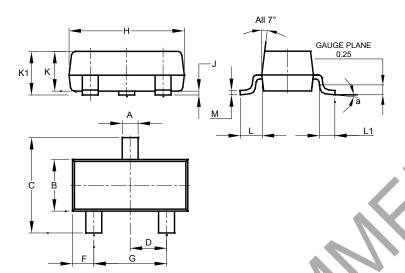


DSS5240T

Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT23

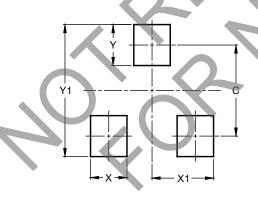


| SOT23 | | | | | | |
|----------------------|-------|-------|-------|--|--|--|
| Dim | Min | Max | Тур | | | |
| A | 0.37 | 0.51 | 0.40 | | | |
| В | 1.20 | 1.40 | 1.30 | | | |
| C | 2.30 | 2.50 | 2.40 | | | |
| D | 0.89 | 1.03 | 0.915 | | | |
| F | 0.45 | 0.60 | 0.535 | | | |
| G | 1.78 | 2.05 | 1.83 | | | |
| Н | 2.80 | 3.00 | 2.90 | | | |
| J | 0.013 | 0.10 | 0.05 | | | |
| K | 0.890 | 1.00 | 0.975 | | | |
| K1 | 0.903 | 1.10 | 1.025 | | | |
| L | 0.45 | 0.61 | 0.55 | | | |
| L1 | 0.25 | 0.55 | 0.40 | | | |
| M | 0.085 | 0.150 | 0.110 | | | |
| а | 0° | 8° | _ | | | |
| All Dimensions in mm | | | | | | |

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT23



| Dimensions | Value (in mm) | | |
|------------|---------------|--|--|
| С | 2.0 | | |
| Х | 0.8 | | |
| X1 | 1.35 | | |
| Y | 0.9 | | |
| Y1 | 2.9 | | |



NOT RECOMMENDED FOR NEW DESIGN USE ZXTP5240F

DSS5240T

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